

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOS III)

TPCF8301

Notebook PC Applications
 Portable Equipment Applications

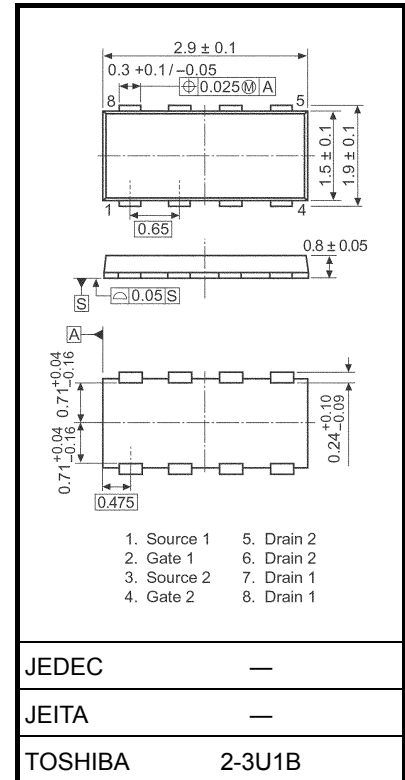
- Low drain-source ON resistance: $R_{DS(ON)} = 72 \text{ m}\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 4.7 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = -10 \text{ }\mu\text{A}$ (max) ($V_{DS} = -20 \text{ V}$)
- Enhancement model: $V_{th} = -0.5 \text{ to } -1.2 \text{ V}$
 ($V_{DS} = -10 \text{ V}$, $I_D = -200 \text{ }\mu\text{A}$)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	-20	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	-20	V
Gate-source voltage		V_{GSS}	± 8	V
Drain current	DC (Note 1)	I_D	-2.7	A
	Pulse (Note 1)	I_{DP}	-10.8	
Drain power dissipation (t = 5 s) (Note 2a)	Single-device operation (Note 3a)	P_D (1)	1.35	W
	Single-device value at dual operation (Note 3b)	P_D (2)	1.12	
Drain power dissipation (t = 5 s) (Note 2b)	Single-device operation (Note 3a)	P_D (1)	0.53	W
	Single-device value at dual operation (Note 3b)	P_D (2)	0.33	
Single pulse avalanche energy (Note 4)		E_{AS}	1.2	mJ
Avalanche current		I_{AR}	-1.35	A
Repetitive avalanche energy Single-device value at dual operation (Note 2a, 3b, 5)		E_{AR}	0.11	mJ
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	-55~150	°C

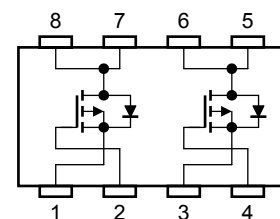
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

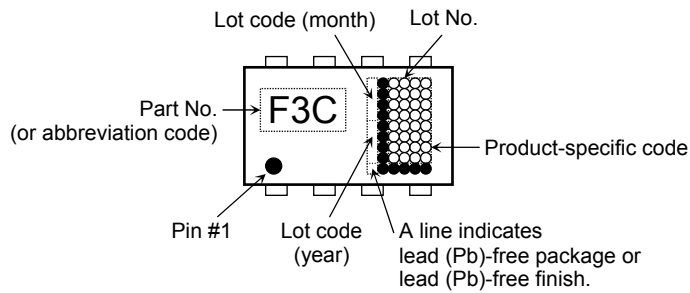


Weight: 0.011 g (typ.)

Circuit Configuration



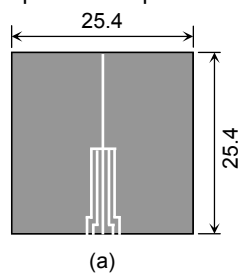
Marking (Note 6)



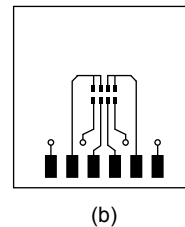
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)

Note 3: a) The power dissipation and thermal resistance values are shown for a single device



FR-4
25.4 × 25.4 × 0.8
(unit: mm)



FR-4
25.4 × 25.4 × 0.8
(unit: mm)

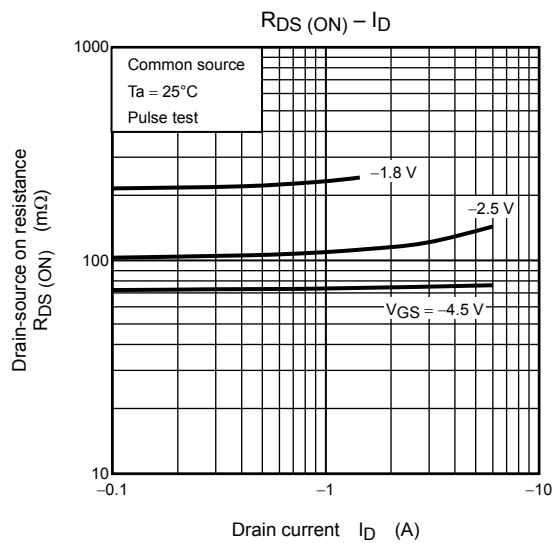
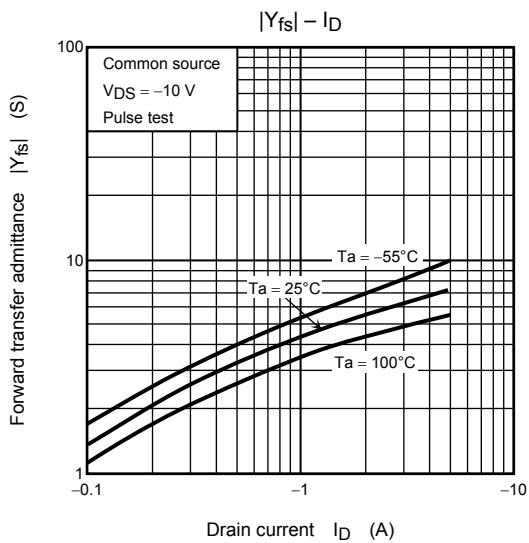
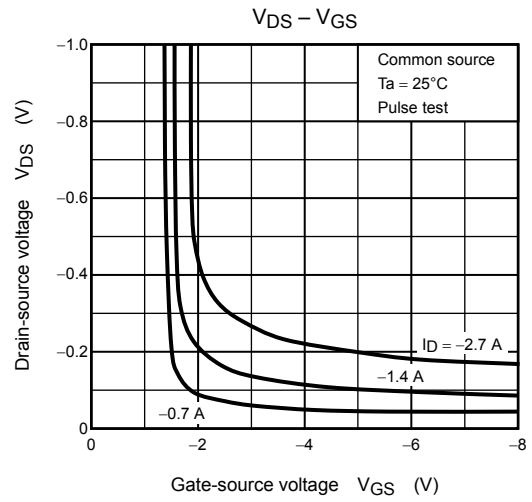
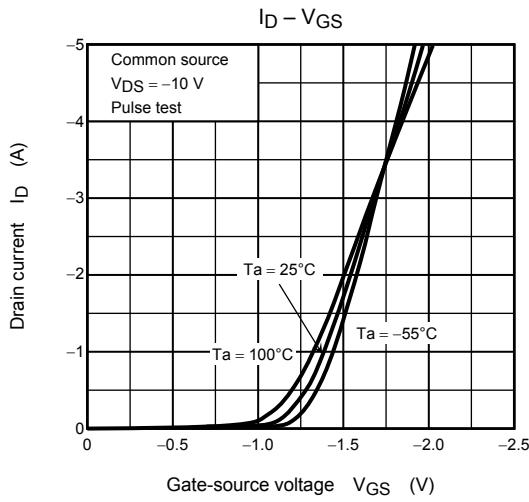
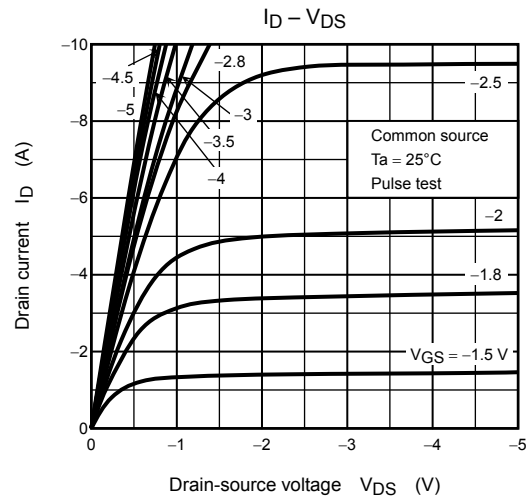
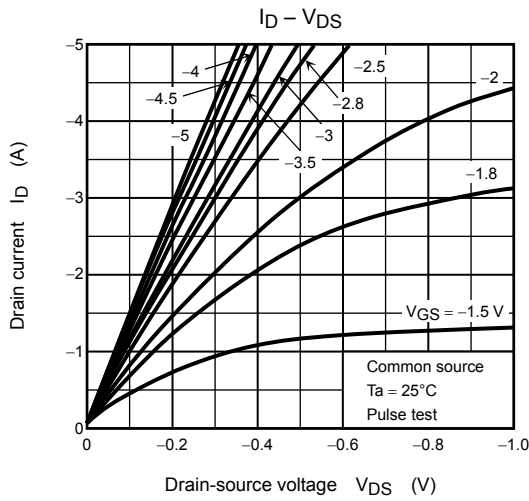
(During single-device operation, power is only applied to one device.)

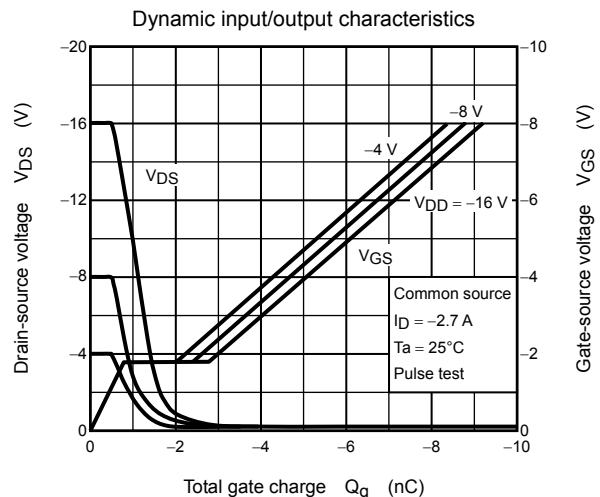
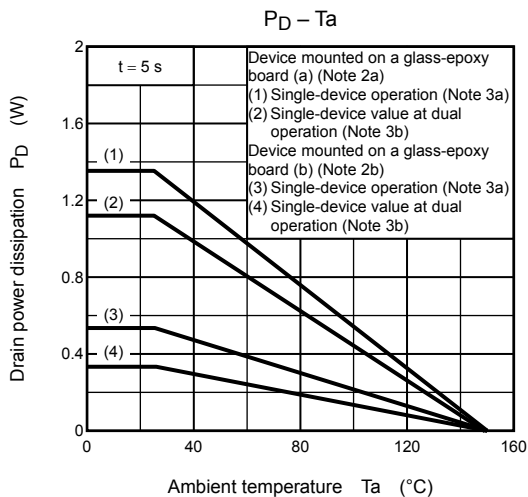
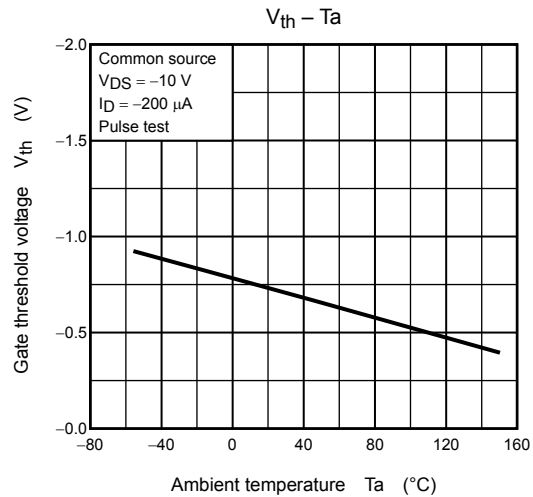
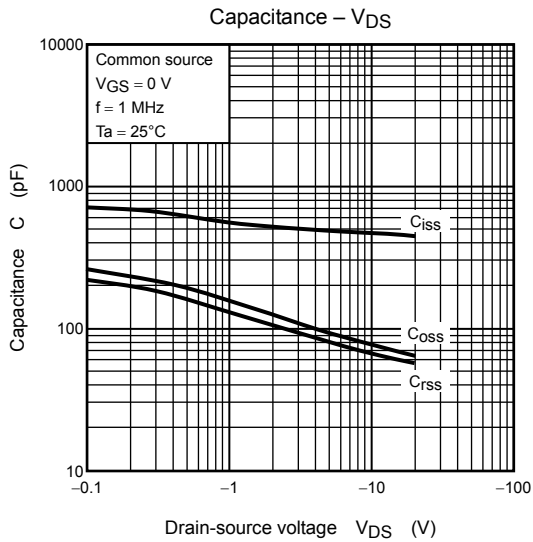
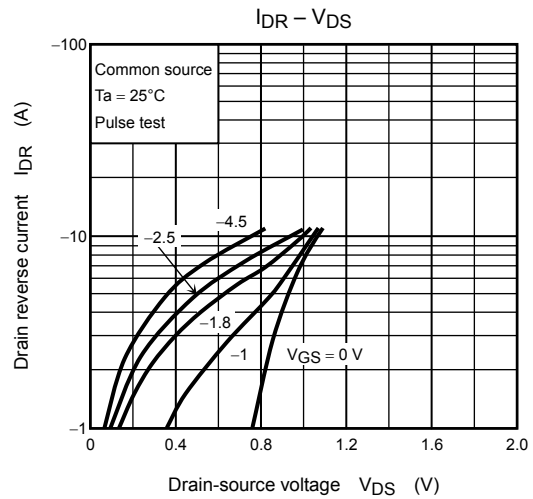
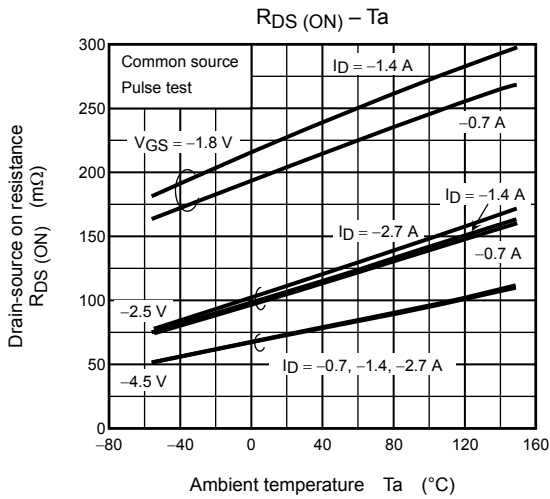
b) The power dissipation and thermal resistance values are shown for a single device (During dual operation, power is evenly applied to both devices.)

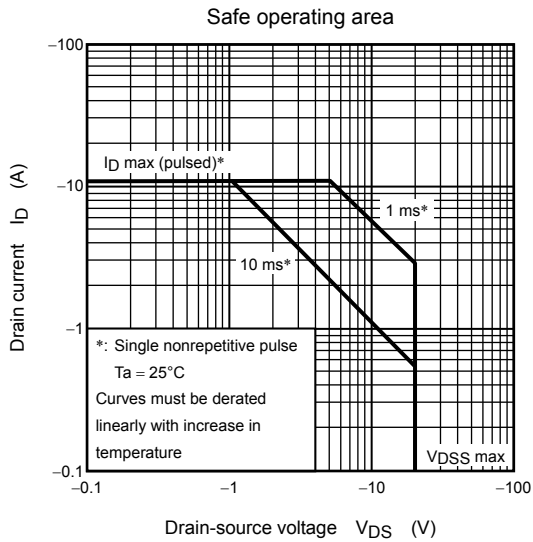
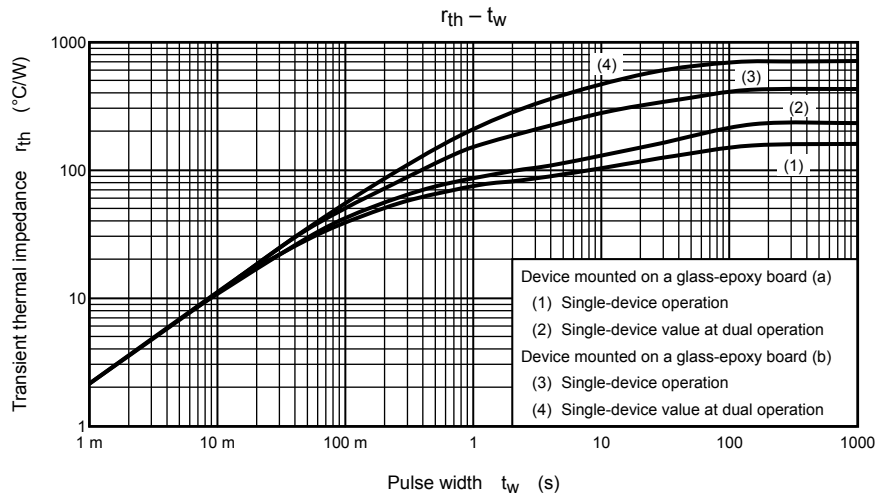
Note 4: $V_{DD} = -16\text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 0.5\text{ mH}$, $R_G = 25\ \Omega$, $I_{AR} = -1.35\text{ A}$

Note 5: Repetitive rating: Pulse width limited by maximum channel temperature.

Note 6: A dot on the lower left of the marking indicates Pin 1







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20070701-EN

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